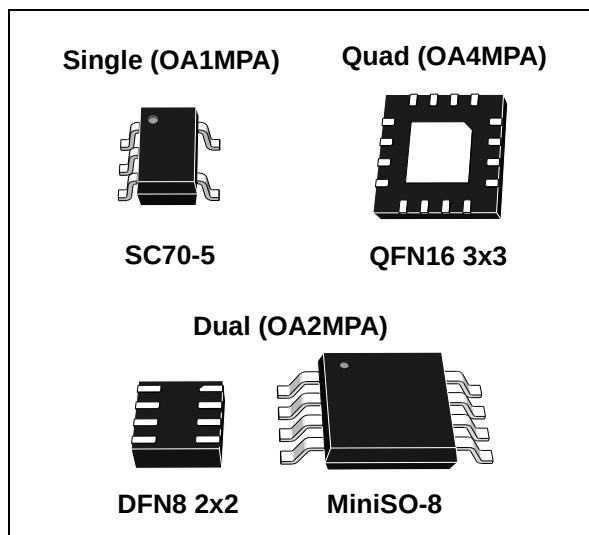




### Features

- Low offset voltage: 200  $\mu\text{V}$  max.
- Low power consumption: 10  $\mu\text{A}$  at 5 V
- Low supply voltage: 1.5 V to 5.5 V
- Gain bandwidth product: 150 kHz typ.
- Low input bias current: 1 pA typ.
- Rail-to-rail input and output
- EMI hardened operational amplifiers
- High tolerance to ESD: 4 kV HBM
- Extended temperature range: -40 to +125  $^{\circ}\text{C}$

### Benefits

- High precision without calibration

- Energy saving
- Guaranteed operation on low-voltage battery

### Applications

- Wearable
- Fitness and healthcare
- Medical instrumentation

### Description

The OA1MPA, OA2MPA, OA4MPA series of single, dual, and quad operational amplifiers offer low-voltage operation, rail-to-rail input and output, and excellent precision ( $V_{\text{IO}}$  lower than 200  $\mu\text{V}$  at 25  $^{\circ}\text{C}$ ).

These low power op amps benefit from STMicroelectronics 5 V CMOS technology and offer an excellent speed/power consumption ratio (150 kHz typical gain bandwidth) while consuming less than 14  $\mu\text{A}$  at 5 V. The OA1MPA, OA2MPA, OA4MPA series also feature an ultra-low input bias current.

The OA1MPA, OA2MPA, OA4MPA are respectively the single, dual and quad operational amplifier versions and are housed in the smallest industrial package.

The OA1MPA, OA2MPA, OA4MPA family is the ideal choice for wearable, fitness and healthcare applications.

Table 1. Device summary

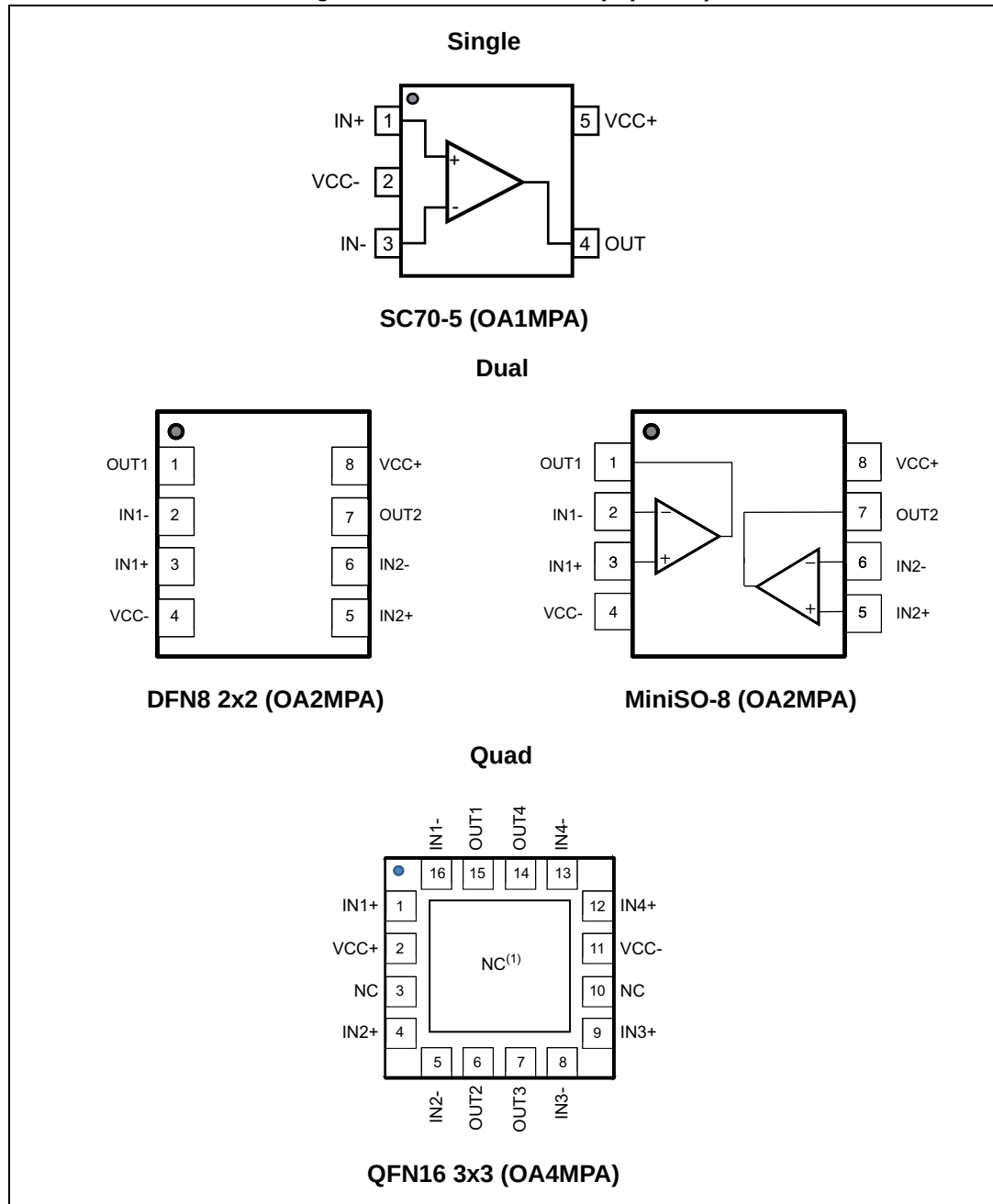
| Order code | Temperature range                                 | Package   | Packaging     | Marking |
|------------|---------------------------------------------------|-----------|---------------|---------|
| OA1MPA22C  | -40 $^{\circ}\text{C}$ to +125 $^{\circ}\text{C}$ | SC70-5    | Tape and reel | K1W     |
| OA2MPA22Q  |                                                   | DFN8 2x2  |               | K1W     |
| OA2MPA34S  |                                                   | MiniSO8   |               | V712    |
| OA4MPA33Q  |                                                   | QFN16 3x3 |               | K1W     |

# Contents

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# 1 Pin connections

Figure 1. Pin connections (top view)



1. The exposed pads of the QFN16 3x3 can be connected to VCC- or left floating.

## 2 Absolute maximum ratings and operating conditions

Table 2. Absolute maximum ratings (AMR)

| Symbol     | Parameter                                                | Value                              | Unit |
|------------|----------------------------------------------------------|------------------------------------|------|
| $V_{CC}$   | Supply voltage <sup>(1)</sup>                            | 6                                  | V    |
| $V_{id}$   | Differential input voltage <sup>(2)</sup>                | $\pm V_{CC}$                       |      |
| $V_{in}$   | Input voltage <sup>(3)</sup>                             | $V_{CC-} - 0.2$ to $V_{CC+} + 0.2$ |      |
| $I_{in}$   | Input current <sup>(4)</sup>                             | 10                                 | mA   |
| $T_{stg}$  | Storage temperature                                      | -65 to +150                        | °C   |
| $R_{thja}$ | Thermal resistance junction-to-ambient <sup>(5)(6)</sup> |                                    | °C/W |
|            | SC70-5                                                   | 205                                |      |
|            | DFN8 2x2                                                 | 120                                |      |
|            | MiniSO8                                                  | 190                                |      |
|            | QFN16 3x3                                                | 45                                 |      |
| $R_{thjc}$ | Thermal resistance junction-to-case DFN8 2x2             | 33                                 |      |
| $T_j$      | Maximum junction temperature                             | 150                                | °C   |
| ESD        | HBM: human body model <sup>(7)</sup>                     | 4                                  | kV   |
|            | MM: machine model for OA1MPA <sup>(8)</sup>              | 150                                | V    |
|            | MM: machine model for OA2MPA <sup>(8)</sup>              | 200                                |      |
|            | MM: machine model for OA4MPA <sup>(8)</sup>              | 300                                |      |
|            | CDM: charged device model except MiniSO8 <sup>(9)</sup>  | 1.5                                | kV   |
|            | CDM: charged device model for MiniSO8 <sup>(9)</sup>     | 1.3                                |      |
|            | Latch-up immunity                                        | 200                                | mA   |

1. All voltage values, except the differential voltage are with respect to the network ground terminal.
2. The differential voltage is a non-inverting input terminal with respect to the inverting input terminal. The OA2MPA and OA4MPA devices include an internal differential voltage limiter that clamps internal differential voltage at 0.5 V.
3.  $V_{CC} - V_{in}$  must not exceed 6 V,  $V_{in}$  must not exceed 6 V.
4. Input current must be limited by a resistor in series with the inputs.
5. Short-circuits can cause excessive heating and destructive dissipation.
6.  $R_{th}$  are typical values.
7. Human body model: 100 pF discharged through a 1.5 k $\Omega$  resistor between two pins of the device, done for all couples of pin combinations with other pins floating.
8. Machine model: a 200 pF cap is charged to the specified voltage, then discharged directly between two pins of the device with no external series resistor (internal resistor < 5  $\Omega$ ), done for all couples of pin combinations with other pins floating.
9. Charged device model: all pins plus package are charged together to the specified voltage and then discharged directly to ground.

Table 3. Operating conditions

| Symbol     | Parameter                            | Value                              | Unit |
|------------|--------------------------------------|------------------------------------|------|
| $V_{CC}$   | Supply voltage                       | 1.5 to 5.5                         | V    |
| $V_{icm}$  | Common mode input voltage range      | $V_{CC-} - 0.1$ to $V_{CC+} + 0.1$ |      |
| $T_{oper}$ | Operating free air temperature range | -40 to +125                        | °C   |

### 3 Electrical characteristics

$V_{CC+} = 1.8\text{ V}$  with  $V_{CC-} = 0\text{ V}$ ,  $V_{icm} = V_{CC}/2$ ,  $T = 25\text{ °C}$ , and  $R_L = 10\text{ k}\Omega$  connected to  $V_{CC}/2$  (unless otherwise specified)

**Table 4. Electrical characteristics**

| Symbol               | Parameter                                                                                                                                                                                   | Conditions                                      | Min. | Typ. | Max.               | Unit    |
|----------------------|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-------------------------------------------------|------|------|--------------------|---------|
| DC performance       |                                                                                                                                                                                             |                                                 |      |      |                    |         |
| V <sub>io</sub>      | Input offset voltage<br>(V <sub>icm</sub> = 0 V)                                                                                                                                            | T = 25 °C                                       |      |      | 200                | μV      |
|                      |                                                                                                                                                                                             | -40 °C < T< 85 °C                               |      |      | 850                |         |
|                      |                                                                                                                                                                                             | -40 °C < T< 125 °C                              |      |      | 1200               |         |
| ΔV <sub>io</sub> /ΔT | Input offset voltage drift                                                                                                                                                                  | -40 °C < T< 125 °C <sup>(1)</sup>               |      |      | 10                 | μV/°C   |
| I <sub>io</sub>      | Input offset current<br>(V <sub>out</sub> = V <sub>CC</sub> /2)                                                                                                                             | T = 25 °C                                       |      | 1    | 10 <sup>(2)</sup>  | pA      |
|                      |                                                                                                                                                                                             | -40 °C < T< 125 °C                              |      | 1    | 300 <sup>(2)</sup> |         |
| I <sub>ib</sub>      | Input bias current (V <sub>out</sub> = V <sub>CC</sub> /2)                                                                                                                                  | T = 25 °C                                       |      | 1    | 10 <sup>(2)</sup>  |         |
|                      |                                                                                                                                                                                             | -40 °C < T< 125 °C                              |      | 1    | 300 <sup>(2)</sup> |         |
| CMR                  | Common mode rejection ratio<br>20 log (ΔV <sub>icm</sub> /ΔV <sub>io</sub> )<br>V <sub>icm</sub> = 0 V to V <sub>CC</sub> ,<br>V <sub>out</sub> = V <sub>CC</sub> /2, R <sub>L</sub> > 1 MΩ | T = 25 °C                                       | 69   | 88   |                    | dB      |
|                      |                                                                                                                                                                                             | -40 °C < T< 125 °C                              | 61   |      |                    |         |
| A <sub>vd</sub>      | Large signal voltage gain<br>V <sub>out</sub> = 0.5 V to (V <sub>CC</sub> - 0.5 V)                                                                                                          | T = 25 °C                                       | 95   |      |                    |         |
|                      |                                                                                                                                                                                             | -40 °C < T< 125 °C                              | 85   |      |                    |         |
| V <sub>OH</sub>      | High level output voltage<br>(V <sub>OH</sub> = V <sub>CC</sub> - V <sub>out</sub> )                                                                                                        | T = 25 °C                                       |      |      | 75                 | mV      |
|                      |                                                                                                                                                                                             | -40 °C < T< 125 °C                              |      |      | 80                 |         |
| V <sub>OL</sub>      | Low level output voltage                                                                                                                                                                    | T = 25 °C                                       |      |      | 40                 |         |
|                      |                                                                                                                                                                                             | -40 °C < T< 125 °C                              |      |      | 60                 |         |
| I <sub>out</sub>     | I <sub>sink</sub> (V <sub>out</sub> = V <sub>CC</sub> )                                                                                                                                     | T = 25 °C                                       | 6    | 12   |                    | mA      |
|                      |                                                                                                                                                                                             | -40 °C < T< 125 °C                              | 4    |      |                    |         |
|                      | I <sub>source</sub> (V <sub>out</sub> = 0 V)                                                                                                                                                | T = 25 °C                                       | 5    | 7    |                    |         |
|                      |                                                                                                                                                                                             | -40 °C < T< 125 °C                              | 3    |      |                    |         |
| I <sub>CC</sub>      | Supply current (per channel,<br>V <sub>out</sub> = V <sub>CC</sub> /2, R <sub>L</sub> > 1 MΩ                                                                                                | T = 25 °C                                       |      | 9    | 14                 | μA      |
|                      |                                                                                                                                                                                             | -40 °C < T< 125 °C                              |      |      | 16                 |         |
| AC performance       |                                                                                                                                                                                             |                                                 |      |      |                    |         |
| GBP                  | Gain bandwidth product                                                                                                                                                                      | R <sub>L</sub> = 10 kΩ, C <sub>L</sub> = 100 pF | 100  | 120  |                    | kHz     |
| F <sub>u</sub>       | Unity gain frequency                                                                                                                                                                        |                                                 |      | 100  |                    |         |
| F <sub>m</sub>       | Phase margin                                                                                                                                                                                |                                                 |      | 45   |                    | Degrees |
| G <sub>m</sub>       | Gain margin                                                                                                                                                                                 |                                                 |      | 19   |                    | dB      |

Table 4. Electrical characteristics (continued)

| Symbol     | Parameter                          | Conditions                                                                                               | Min. | Typ. | Max. | Unit                                 |
|------------|------------------------------------|----------------------------------------------------------------------------------------------------------|------|------|------|--------------------------------------|
| SR         | Slew rate <sup>(3)</sup>           | $R_L = 10\text{ k}\Omega$ , $C_L = 100\text{ pF}$ ,<br>$V_{out} = 0.5\text{ V to }V_{CC} - 0.5\text{ V}$ |      | 0.04 |      | V/ $\mu$ s                           |
| $e_n$      | Equivalent input noise voltage     | $f = 1\text{ kHz}$                                                                                       |      | 100  |      | $\frac{\text{nV}}{\sqrt{\text{Hz}}}$ |
|            |                                    | $f = 10\text{ kHz}$                                                                                      |      | 96   |      |                                      |
| $t_{init}$ | Initialization time <sup>(4)</sup> | $T = 25\text{ }^\circ\text{C}$                                                                           |      |      | 5    | ms                                   |
|            |                                    | $-40\text{ }^\circ\text{C} < T < 125\text{ }^\circ\text{C}$                                              |      |      | 60   |                                      |

1. See [Section 4.4: Input offset voltage drift over temperature](#).
2. Guaranteed by characterization.
3. Slew rate value is calculated as the average between positive and negative slew rates.
4. Initialization time is defined as the delay after power-up to guarantee operation within specified performances. Guaranteed by design. See [Section 4.6: Initialization time](#).

$V_{CC+} = 3.3 \text{ V}$  with  $V_{CC-} = 0 \text{ V}$ ,  $V_{icm} = V_{CC}/2$ ,  $T = 25 \text{ }^{\circ}\text{C}$ , and  $R_L = 10 \text{ k}\Omega$  connected to  $V_{CC}/2$  (unless otherwise specified)

Table 5. Electrical characteristics

| Symbol               | Parameter                                                                                                                                                                                   | Conditions                                                                                              | Min. | Typ. | Max.               | Unit                                      |
|----------------------|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|---------------------------------------------------------------------------------------------------------|------|------|--------------------|-------------------------------------------|
| DC performance       |                                                                                                                                                                                             |                                                                                                         |      |      |                    |                                           |
| V <sub>io</sub>      | Input offset voltage                                                                                                                                                                        | T = 25 °C                                                                                               |      |      | 200                | μV                                        |
|                      |                                                                                                                                                                                             | -40 °C < T< 85 °C                                                                                       |      |      | 850                |                                           |
|                      |                                                                                                                                                                                             | -40 °C < T< 125 °C                                                                                      |      |      | 1200               |                                           |
| ΔV <sub>io</sub> /ΔT | Input offset voltage drift                                                                                                                                                                  | -40 °C < T< 125 °C <sup>(1)</sup>                                                                       |      |      | 10                 | μV/°C                                     |
| ΔV <sub>io</sub>     | Long-term input offset voltage drift                                                                                                                                                        | T = 25 °C <sup>(2)</sup>                                                                                |      | 0.3  |                    | $\frac{\mu\text{V}}{\sqrt{\text{month}}}$ |
| I <sub>io</sub>      | Input offset current<br>(V <sub>out</sub> = V <sub>CC</sub> /2)                                                                                                                             | T = 25 °C                                                                                               |      | 1    | 10 <sup>(3)</sup>  | pA                                        |
|                      |                                                                                                                                                                                             | -40 °C < T< 125 °C                                                                                      |      | 1    | 300 <sup>(3)</sup> |                                           |
| I <sub>ib</sub>      | Input bias current (V <sub>out</sub> = V <sub>CC</sub> /2)                                                                                                                                  | T = 25 °C                                                                                               |      | 1    | 10 <sup>(3)</sup>  |                                           |
|                      |                                                                                                                                                                                             | -40 °C < T< 125 °C                                                                                      |      | 1    | 300 <sup>(3)</sup> |                                           |
| CMR                  | Common mode rejection ratio<br>20 log (ΔV <sub>icm</sub> /ΔV <sub>io</sub> )<br>V <sub>icm</sub> = 0 V to V <sub>CC</sub> , V <sub>out</sub> = V <sub>CC</sub> /2,<br>R <sub>L</sub> > 1 MΩ | T = 25 °C                                                                                               | 80   | 100  |                    | dB                                        |
|                      |                                                                                                                                                                                             | -40 °C < T< 125 °C                                                                                      | 69   |      |                    |                                           |
| A <sub>vd</sub>      | Large signal voltage gain<br>V <sub>out</sub> = 0.5 V to (V <sub>CC</sub> - 0.5 V)                                                                                                          | T = 25 °C                                                                                               | 95   |      |                    |                                           |
|                      |                                                                                                                                                                                             | -40 °C < T< 125 °C                                                                                      | 85   |      |                    |                                           |
| V <sub>OH</sub>      | High level output voltage<br>(V <sub>OH</sub> = V <sub>CC</sub> - V <sub>out</sub> )                                                                                                        | T = 25 °C                                                                                               |      |      | 75                 | mV                                        |
|                      |                                                                                                                                                                                             | -40 °C < T< 125 °C                                                                                      |      |      | 80                 |                                           |
| V <sub>OL</sub>      | Low level output voltage                                                                                                                                                                    | T = 25 °C                                                                                               |      |      | 40                 |                                           |
|                      |                                                                                                                                                                                             | -40 °C < T< 125 °C                                                                                      |      |      | 60                 |                                           |
| I <sub>out</sub>     | I <sub>sink</sub> (V <sub>out</sub> = V <sub>CC</sub> )                                                                                                                                     | T = 25 °C                                                                                               | 20   | 34   |                    | mA                                        |
|                      |                                                                                                                                                                                             | -40 °C < T< 125 °C                                                                                      | 15   |      |                    |                                           |
|                      | I <sub>source</sub> (V <sub>out</sub> = 0 V)                                                                                                                                                | T = 25 °C                                                                                               | 20   | 26   |                    |                                           |
|                      |                                                                                                                                                                                             | -40 °C < T< 125 °C                                                                                      | 15   |      |                    |                                           |
| I <sub>CC</sub>      | Supply current (per channel,<br>V <sub>out</sub> = V <sub>CC</sub> /2, R <sub>L</sub> > 1 MΩ)                                                                                               | T = 25 °C                                                                                               |      | 9    | 14                 | μA                                        |
|                      |                                                                                                                                                                                             | -40 °C < T< 125 °C                                                                                      |      |      | 16                 |                                           |
| AC performance       |                                                                                                                                                                                             |                                                                                                         |      |      |                    |                                           |
| GBP                  | Gain bandwidth product                                                                                                                                                                      | R <sub>L</sub> = 10 kΩ, C <sub>L</sub> = 100 pF                                                         | 100  | 120  |                    | kHz                                       |
| F <sub>u</sub>       | Unity gain frequency                                                                                                                                                                        |                                                                                                         |      | 100  |                    |                                           |
| F <sub>m</sub>       | Phase margin                                                                                                                                                                                |                                                                                                         |      | 45   |                    | Degrees                                   |
| G <sub>m</sub>       | Gain margin                                                                                                                                                                                 |                                                                                                         |      | 19   |                    | dB                                        |
| SR                   | Slew rate <sup>(4)</sup>                                                                                                                                                                    | R <sub>L</sub> = 10 kΩ, C <sub>L</sub> = 100 pF,<br>V <sub>out</sub> = 0.5 V to V <sub>CC</sub> - 0.5 V |      | 0.05 |                    | V/μs                                      |

Table 5. Electrical characteristics (continued)

| Symbol            | Parameter                          | Conditions                                                        | Min. | Typ. | Max. | Unit                                 |
|-------------------|------------------------------------|-------------------------------------------------------------------|------|------|------|--------------------------------------|
| $e_n$             | Equivalent input noise voltage     | $f = 1 \text{ kHz}$                                               |      | 100  |      | $\frac{\text{nV}}{\sqrt{\text{Hz}}}$ |
|                   |                                    | $f = 10 \text{ kHz}$                                              |      | 96   |      |                                      |
| $t_{\text{init}}$ | Initialization time <sup>(5)</sup> | $T = 25 \text{ }^{\circ}\text{C}$                                 |      |      | 5    | ms                                   |
|                   |                                    | $-40 \text{ }^{\circ}\text{C} < T < 125 \text{ }^{\circ}\text{C}$ |      |      | 50   |                                      |

1. See [Section 4.4: Input offset voltage drift over temperature](#).
2. Typical value is based on the  $V_{io}$  drift observed after 1000h at 125 °C extrapolated to 25 °C using the Arrhenius law and assuming an activation energy of 0.7 eV. The operational amplifier is aged in follower mode configuration. See [Section 4.5: Long-term input offset voltage drift](#).
3. Guaranteed by characterization.
4. Slew rate value is calculated as the average between positive and negative slew rates.
5. Initialization time is defined as the delay after power-up which guarantees operation within specified performances. Guaranteed by design. See [Section 4.6: Initialization time](#).

$V_{CC+} = 5\text{ V}$  with  $V_{CC-} = 0\text{ V}$ ,  $V_{icm} = V_{CC}/2$ ,  $T = 25\text{ }^{\circ}\text{C}$ , and  $R_L = 10\text{ k}\Omega$  connected to  $V_{CC}/2$  (unless otherwise specified)

Table 6. Electrical characteristics

| Symbol                   | Parameter                                                                                                                                                                 | Conditions                                                            | Min. | Typ.       | Max.        | Unit                                      |
|--------------------------|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-----------------------------------------------------------------------|------|------------|-------------|-------------------------------------------|
| <b>DC performance</b>    |                                                                                                                                                                           |                                                                       |      |            |             |                                           |
| $V_{io}$                 | Input offset voltage                                                                                                                                                      | $T = 25\text{ }^{\circ}\text{C}$                                      |      |            | 200         | $\mu\text{V}$                             |
|                          |                                                                                                                                                                           | $-40\text{ }^{\circ}\text{C} < T < 85\text{ }^{\circ}\text{C}$        |      |            | 850         |                                           |
|                          |                                                                                                                                                                           | $-40\text{ }^{\circ}\text{C} < T < 125\text{ }^{\circ}\text{C}$       |      |            | 1200        |                                           |
| $\Delta V_{io}/\Delta T$ | Input offset voltage drift                                                                                                                                                | $-40\text{ }^{\circ}\text{C} < T < 125\text{ }^{\circ}\text{C}^{(1)}$ |      |            | 10          | $\mu\text{V}/^{\circ}\text{C}$            |
| $\Delta V_{io}$          | Long-term input offset voltage drift                                                                                                                                      | $T = 25\text{ }^{\circ}\text{C}^{(2)}$                                |      | 0.7        |             | $\frac{\mu\text{V}}{\sqrt{\text{month}}}$ |
| $I_{io}$                 | Input offset current<br>( $V_{out} = V_{CC}/2$ )                                                                                                                          | $T = 25\text{ }^{\circ}\text{C}$                                      |      | 1          | $10^{(3)}$  | $\text{pA}$                               |
|                          |                                                                                                                                                                           | $-40\text{ }^{\circ}\text{C} < T < 125\text{ }^{\circ}\text{C}$       |      | 1          | $300^{(3)}$ |                                           |
| $I_{ib}$                 | Input bias current<br>( $V_{out} = V_{CC}/2$ )                                                                                                                            | $T = 25\text{ }^{\circ}\text{C}$                                      |      | 1          | $10^{(3)}$  |                                           |
|                          |                                                                                                                                                                           | $-40\text{ }^{\circ}\text{C} < T < 125\text{ }^{\circ}\text{C}$       |      | 1          | $300^{(3)}$ |                                           |
| CMR                      | Common mode rejection ratio<br>$20 \log (\Delta V_{icm}/\Delta V_{io})$<br>$V_{icm} = 0\text{ V to } V_{CC}$ ,<br>$V_{out} = V_{CC}/2$ , $R_L > 1\text{ M}\Omega$         | $T = 25\text{ }^{\circ}\text{C}$                                      | 74   | 94         |             | $\text{dB}$                               |
|                          |                                                                                                                                                                           | $-40\text{ }^{\circ}\text{C} < T < 125\text{ }^{\circ}\text{C}$       | 73   |            |             |                                           |
| SVR                      | Supply voltage rejection ratio<br>$20 \log (\Delta V_{CC}/\Delta V_{io})$<br>$V_{CC} = 1.5\text{ to } 5.5\text{ V}$ , $V_{ic} = 0\text{ V}$ ,<br>$R_L > 1\text{ M}\Omega$ | $T = 25\text{ }^{\circ}\text{C}$                                      | 71   | 90         |             |                                           |
|                          |                                                                                                                                                                           | $-40\text{ }^{\circ}\text{C} < T < 125\text{ }^{\circ}\text{C}$       | 71   |            |             |                                           |
| $A_{vd}$                 | Large signal voltage gain<br>$V_{out} = 0.5\text{ V to } (V_{CC} - 0.5\text{ V})$                                                                                         | $T = 25\text{ }^{\circ}\text{C}$                                      | 95   |            |             |                                           |
|                          |                                                                                                                                                                           | $-40\text{ }^{\circ}\text{C} < T < 125\text{ }^{\circ}\text{C}$       | 85   |            |             |                                           |
| EMIRR                    | EMI rejection ratio<br>$\text{EMIRR} = 20 \log (V_{RFpeak}/\Delta V_{io})$                                                                                                | $V_{RF} = 100\text{ mVRFpeak}$ , $f = 400\text{ MHz}$                 |      | $38^{(4)}$ |             |                                           |
|                          |                                                                                                                                                                           | $V_{RF} = 100\text{ mVRFpeak}$ , $f = 900\text{ MHz}$                 |      | $50^{(4)}$ |             |                                           |
|                          |                                                                                                                                                                           | $V_{RF} = 100\text{ mVRFpeak}$ , $f = 1800\text{ MHz}$                |      | $60^{(4)}$ |             |                                           |
|                          |                                                                                                                                                                           | $V_{RF} = 100\text{ mVRFpeak}$ , $f = 2400\text{ MHz}$                |      | $63^{(4)}$ |             |                                           |
| $V_{OH}$                 | High level output voltage<br>( $V_{OH} = V_{CC} - V_{out}$ )                                                                                                              | $T = 25\text{ }^{\circ}\text{C}$                                      |      |            | 75          | $\text{mV}$                               |
|                          |                                                                                                                                                                           | $-40\text{ }^{\circ}\text{C} < T < 125\text{ }^{\circ}\text{C}$       |      |            | 80          |                                           |
| $V_{OL}$                 | Low level output voltage                                                                                                                                                  | $T = 25\text{ }^{\circ}\text{C}$                                      |      |            | 40          |                                           |
|                          |                                                                                                                                                                           | $-40\text{ }^{\circ}\text{C} < T < 125\text{ }^{\circ}\text{C}$       |      |            | 60          |                                           |
| $I_{out}$                | $I_{sink} (V_{out} = V_{CC})$                                                                                                                                             | $T = 25\text{ }^{\circ}\text{C}$                                      | 35   | 56         |             | $\text{mA}$                               |
|                          |                                                                                                                                                                           | $-40\text{ }^{\circ}\text{C} < T < 125\text{ }^{\circ}\text{C}$       | 20   |            |             |                                           |
|                          | $I_{source} (V_{out} = 0\text{ V})$                                                                                                                                       | $T = 25\text{ }^{\circ}\text{C}$                                      | 35   | 45         |             |                                           |
|                          |                                                                                                                                                                           | $-40\text{ }^{\circ}\text{C} < T < 125\text{ }^{\circ}\text{C}$       | 20   |            |             |                                           |

Table 6. Electrical characteristics (continued)

| Symbol            | Parameter                                                                                  | Conditions                                                                                                                                                               | Min. | Typ.  | Max. | Unit                   |
|-------------------|--------------------------------------------------------------------------------------------|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------|------|-------|------|------------------------|
| I <sub>CC</sub>   | Supply current (per channel, V <sub>out</sub> = V <sub>CC</sub> /2, R <sub>L</sub> > 1 MΩ) | T = 25 °C                                                                                                                                                                |      | 10    | 14   | μA                     |
|                   |                                                                                            | -40 °C < T< 125 °C                                                                                                                                                       |      |       | 16   |                        |
| AC performance    |                                                                                            |                                                                                                                                                                          |      |       |      |                        |
| GBP               | Gain bandwidth product                                                                     | R <sub>L</sub> = 10 kΩ, C <sub>L</sub> = 100 pF                                                                                                                          | 110  | 150   |      | kHz                    |
| F <sub>u</sub>    | Unity gain frequency                                                                       |                                                                                                                                                                          |      | 120   |      |                        |
| F <sub>m</sub>    | Phase margin                                                                               |                                                                                                                                                                          |      | 45    |      | Degrees                |
| G <sub>m</sub>    | Gain margin                                                                                |                                                                                                                                                                          |      | 19    |      | dB                     |
| SR                | Slew rate <sup>(5)</sup>                                                                   | R <sub>L</sub> = 10 kΩ, C <sub>L</sub> = 100 pF, V <sub>out</sub> = 0.5 V to V <sub>CC</sub> - 0.5 V                                                                     |      | 0.06  |      | V/μs                   |
| ∫e <sub>n</sub>   | Low-frequency peak-to-peak input noise                                                     | Bandwidth: f = 0.1 to 10 Hz                                                                                                                                              |      | 10    |      | μV <sub>pp</sub>       |
| e <sub>n</sub>    | Equivalent input noise voltage                                                             | f = 1 kHz                                                                                                                                                                |      | 100   |      | $\frac{nV}{\sqrt{Hz}}$ |
|                   |                                                                                            | f = 10 kHz                                                                                                                                                               |      | 96    |      |                        |
| THD+N             | Total harmonic distortion + noise                                                          | f <sub>in</sub> = 1 kHz, A <sub>CL</sub> = 1, R <sub>L</sub> = 100 kΩ, V <sub>icm</sub> = (V <sub>CC</sub> - 1 V)/2, BW = 22 kHz, V <sub>out</sub> = 0.5 V <sub>pp</sub> |      | 0.008 |      | %                      |
| t <sub>init</sub> | Initialization time <sup>(6)</sup>                                                         | T = 25 °C                                                                                                                                                                |      |       | 5    | ms                     |
|                   |                                                                                            | -40 °C < T< 125 °C                                                                                                                                                       |      |       | 50   |                        |

1. See [Section 4.4: Input offset voltage drift over temperature](#).
2. Typical value is based on the  $V_{io}$  drift observed after 1000h at  $125\text{ }^{\circ}\text{C}$  extrapolated to  $25\text{ }^{\circ}\text{C}$  using the Arrhenius law and assuming an activation energy of  $0.7\text{ eV}$ . The operational amplifier is aged in follower mode configuration. See [Section 4.5: Long-term input offset voltage drift](#).
3. Guaranteed by characterization.
4. Tested on SC70-5 package.
5. Slew rate value is calculated as the average between positive and negative slew rates.
6. Initialization time is defined as the delay after power-up to guarantee operation within specified performances. Guaranteed by design. See [Section 4.6: Initialization time](#).

**Figure 2. Supply current vs. supply voltage at  $V_{icm} = V_{CC}/2$**

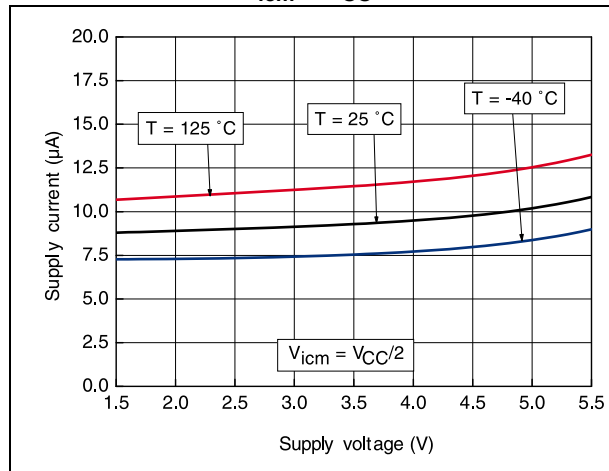


**Figure 3. Input offset voltage distribution at  $V_{CC} = 5\text{ V}$ ,  $V_{icm} = V_{CC}/2$**

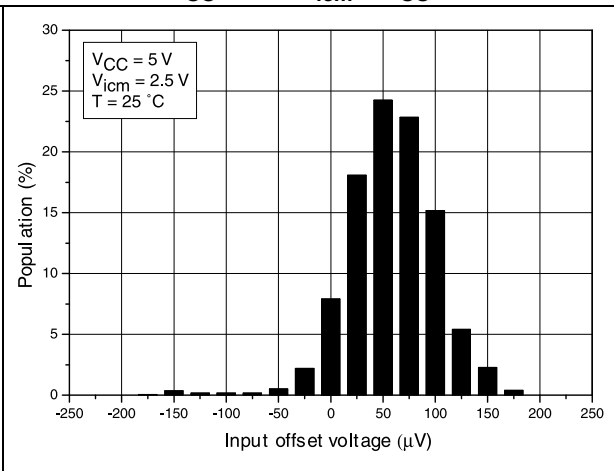


**Figure 4. Input offset voltage distribution at  $V_{CC} = 3.3\text{ V}$ ,  $V_{icm} = V_{CC}/2$**

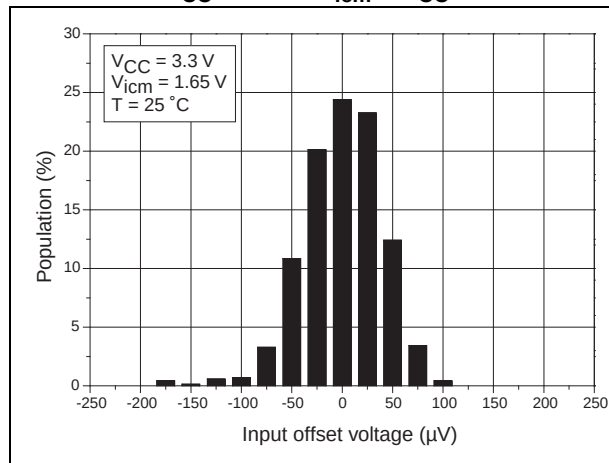


**Figure 5. Input offset voltage temperature coefficient distribution**

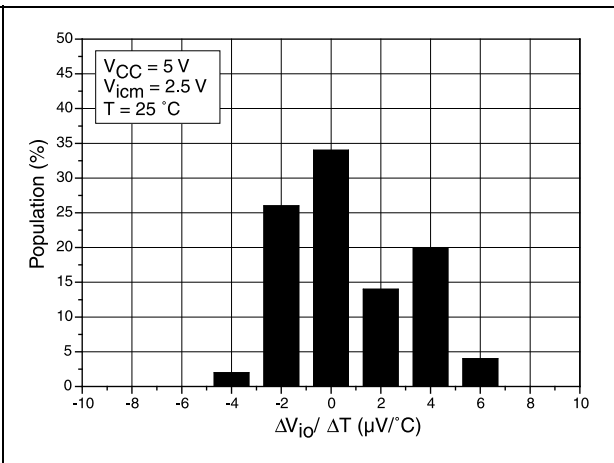


**Figure 6. Input offset voltage vs. input common mode voltage**

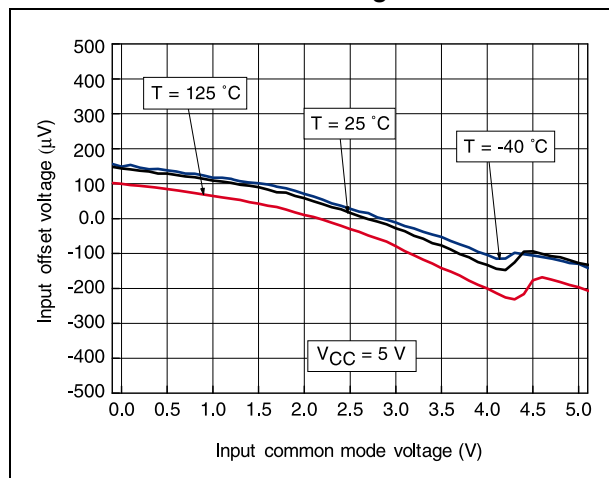


**Figure 7. Input offset voltage vs. temperature**

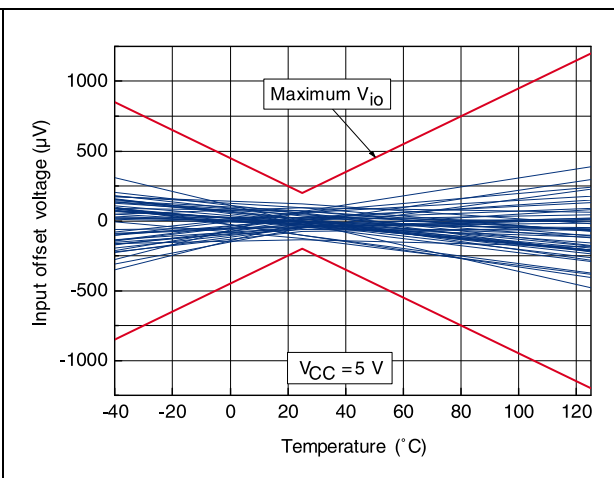


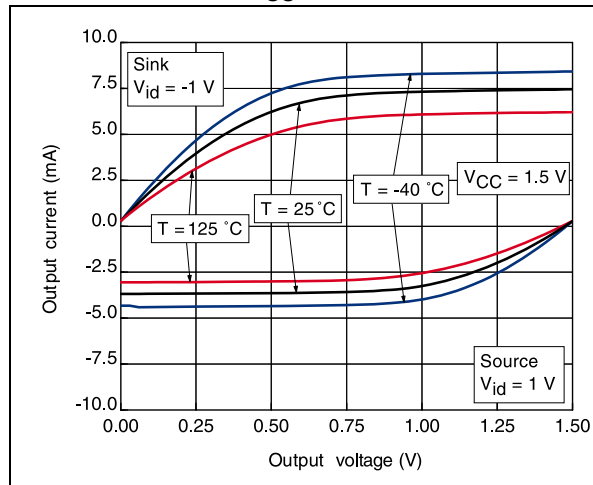
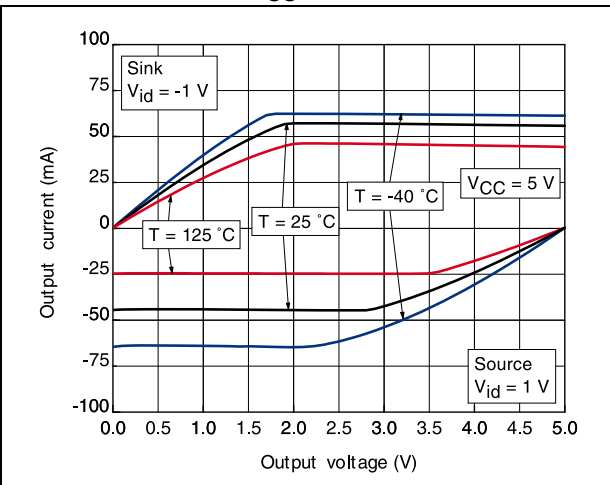
Figure 8. Output current vs. output voltage at  $V_{CC} = 1.5\text{ V}$ Figure 9. Output current vs. output voltage at  $V_{CC} = 5\text{ V}$ 

Figure 10. Output current vs. supply voltage

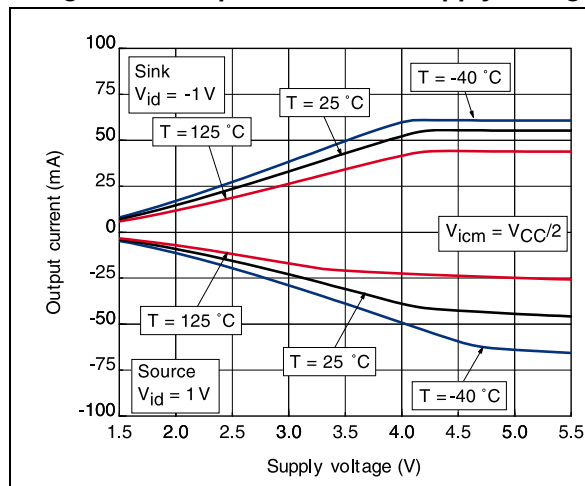
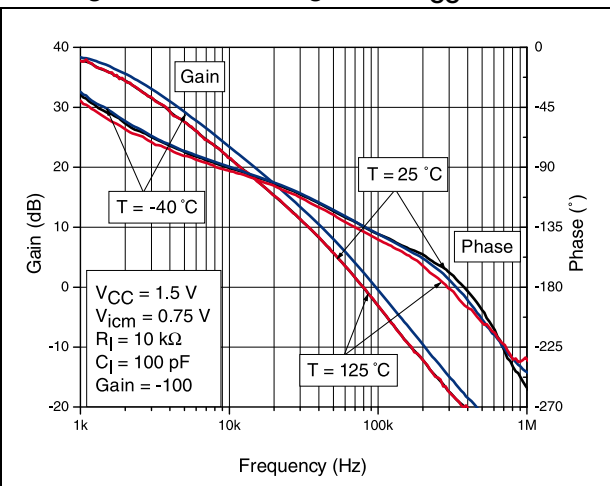
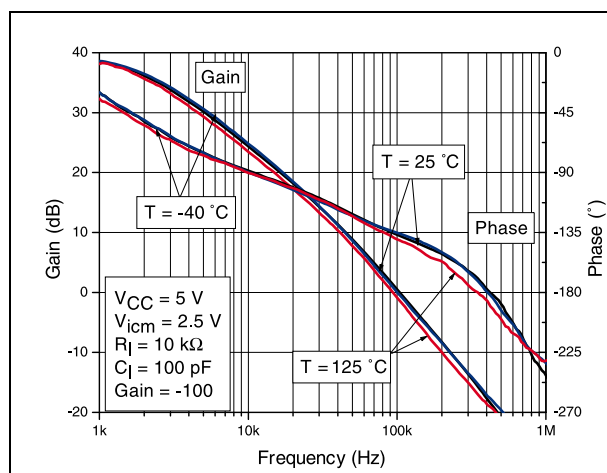
Figure 11. Bode diagram at  $V_{CC} = 1.5\text{ V}$ Figure 12. Bode diagram at  $V_{CC} = 5\text{ V}$ 

Figure 13. Closed-loop gain diagram vs. capacitive load

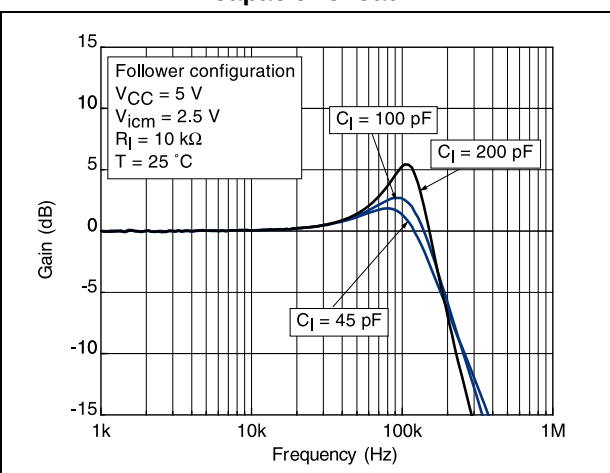


Figure 14. Positive slew rate

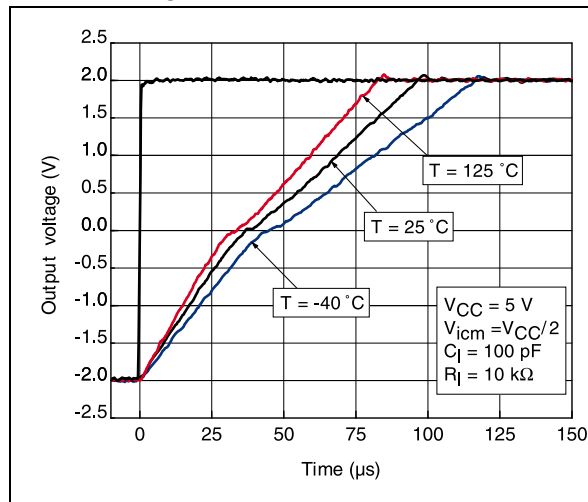


Figure 15. Negative slew rate

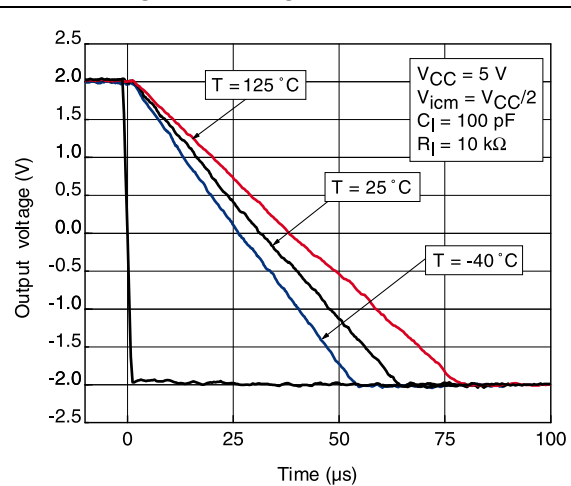


Figure 16. Slew rate vs. supply voltage

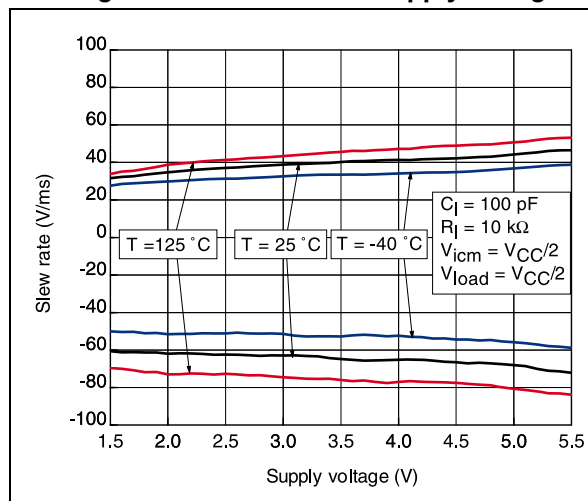


Figure 17. Noise vs. frequency

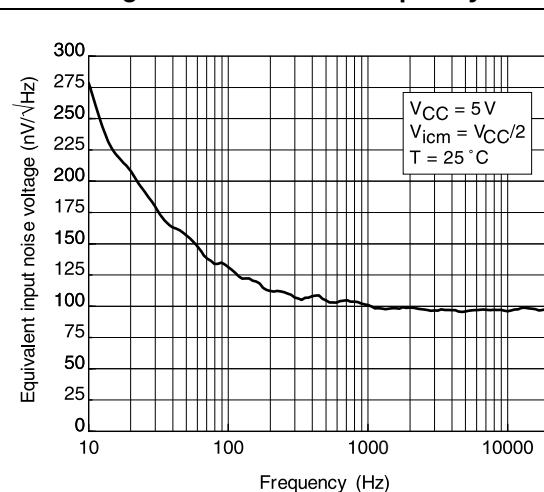


Figure 18. 0.1 Hz to 10 Hz noise

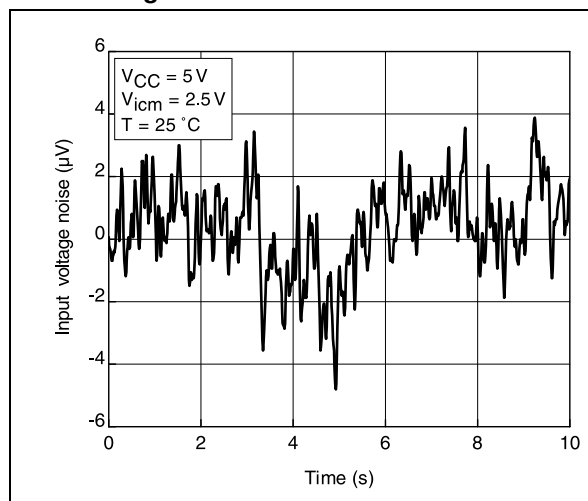


Figure 19. THD+N vs. frequency

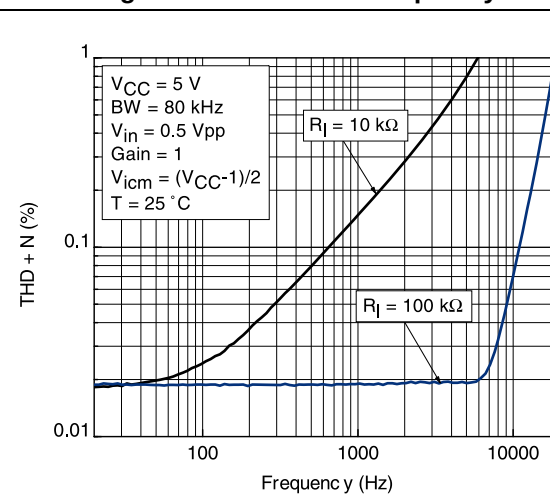


Figure 20. THD+N vs. output voltage

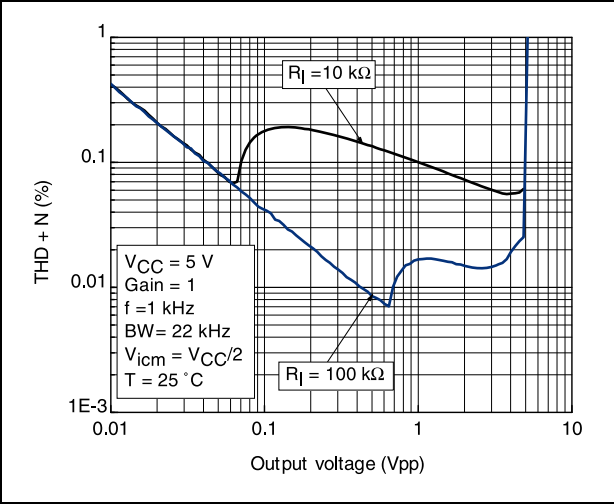
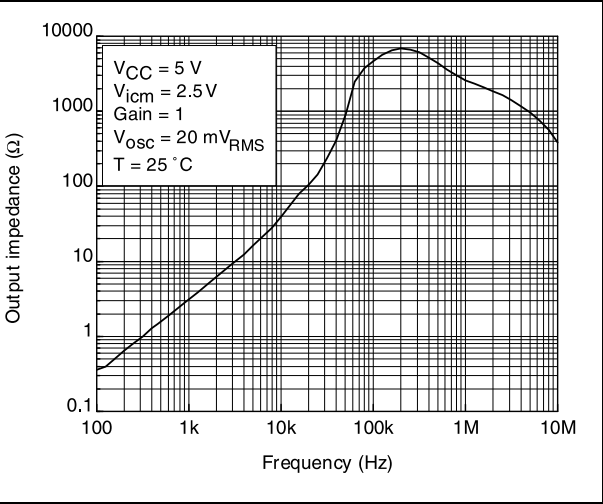


Figure 21. Output impedance vs. frequency in closed-loop configuration



## 4 Application information

### 4.1 Operating voltages

The OA1MPA, OA2MPA, and OA4MPA series of devices can operate from 1.5 V to 5.5 V. The parameters are fully specified for 1.8 V, 3.3 V, and 5 V power supplies. However, they are very stable in the full  $V_{CC}$  range and several characterization curves show OA1MPA, OA2MPA, and OA4MPA device characteristics at 1.5 V. In addition, the main specifications are guaranteed in the extended temperature range from -40 °C to +125 °C.

### 4.2 Rail-to-rail input

The OA1MPA, OA2MPA, and OA4MPA devices have a rail-to-rail input, and the input common mode range is extended from  $V_{CC-} - 0.1$  V to  $V_{CC+} + 0.1$  V.

### 4.3 Rail-to-rail output

The output levels of the OA1MPA, OA2MPA, and OA4MPA operational amplifiers can go close to the rails: to a maximum of 40 mV below the upper rail and to a maximum of 75 mV above the lower rail when a 10 k $\Omega$  resistive load is connected to  $V_{CC}/2$ .

### 4.4 Input offset voltage drift over temperature

The maximum input voltage drift over the temperature variation is defined as the offset variation related to offset value measured at 25 °C. The operational amplifier is one of the main circuits of the signal conditioning chain, and the amplifier input offset is a major contributor to the chain accuracy. The signal chain accuracy at 25 °C can be compensated during production at application level. The maximum input voltage drift over temperature enables the system designer to anticipate the effect of temperature variations.

The maximum input voltage drift over temperature is computed using [Equation 1](#).

#### Equation 1

$$\frac{\Delta V_{io}}{\Delta T} = \max \left| \frac{V_{io}(T) - V_{io}(25^{\circ}\text{C})}{T - 25^{\circ}\text{C}} \right|$$

with  $T = -40$  °C and  $125$  °C.

The datasheet maximum value is guaranteed by a measurement on a representative sample size ensuring a  $C_{pk}$  (process capability index) greater than 1.33.

## 4.5 Long-term input offset voltage drift

To evaluate product reliability, two types of stress acceleration are used:

- Voltage acceleration, by changing the applied voltage
- Temperature acceleration, by changing the die temperature (below the maximum junction temperature allowed by the technology) with the ambient temperature.

The voltage acceleration has been defined based on JEDEC results, and is defined using [Equation 2](#).

### Equation 2

$$A_{FV} = e^{\beta \cdot (V_S - V_U)}$$

Where:

$A_{FV}$  is the voltage acceleration factor

$\beta$  is the voltage acceleration constant in 1/V, constant technology parameter ( $\beta = 1$ )

$V_S$  is the stress voltage used for the accelerated test

$V_U$  is the voltage used for the application

The temperature acceleration is driven by the Arrhenius model, and is defined in [Equation 3](#).

### Equation 3

$$A_{FT} = e^{\frac{E_a}{k} \cdot \left( \frac{1}{T_U} - \frac{1}{T_S} \right)}$$

Where:

$A_{FT}$  is the temperature acceleration factor

$E_a$  is the activation energy of the technology based on the failure rate

$k$  is the Boltzmann constant ( $8.6173 \times 10^{-5} \text{ eV.K}^{-1}$ )

$T_U$  is the temperature of the die when  $V_U$  is used (K)

$T_S$  is the temperature of the die under temperature stress (K)

The final acceleration factor,  $A_F$ , is the multiplication of the voltage acceleration factor and the temperature acceleration factor ([Equation 4](#)).

### Equation 4

$$A_F = A_{FT} \times A_{FV}$$

$A_F$  is calculated using the temperature and voltage defined in the mission profile of the product. The  $A_F$  value can then be used in [Equation 5](#) to calculate the number of months of use equivalent to 1000 hours of reliable stress duration.

**Equation 5**

$$\text{Months} = A_F \times 1000 \text{ h} \times 12 \text{ months} / (24 \text{ h} \times 365.25 \text{ days})$$

To evaluate the op amp reliability, a follower stress condition is used where  $V_{CC}$  is defined as a function of the maximum operating voltage and the absolute maximum rating (as recommended by JEDEC rules).

The  $V_{io}$  drift (in  $\mu\text{V}$ ) of the product after 1000 h of stress is tracked with parameters at different measurement conditions (see [Equation 6](#)).

**Equation 6**

$$V_{CC} = \max V_{op} \text{ with } V_{icm} = V_{CC} / 2$$

The long term drift parameter ( $\Delta V_{io}$ ), estimating the reliability performance of the product, is obtained using the ratio of the  $V_{io}$  (input offset voltage value) drift over the square root of the calculated number of months ([Equation 7](#)).

**Equation 7**

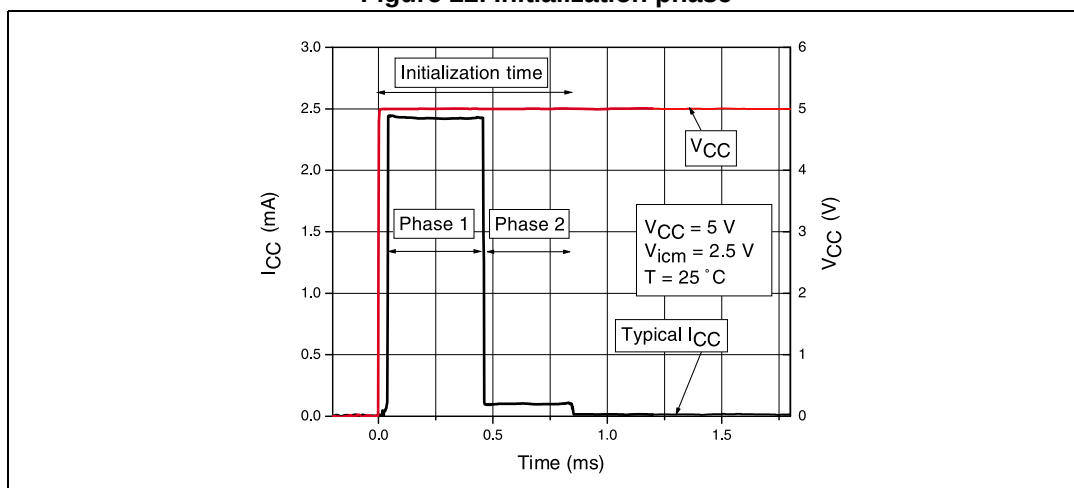
$$\Delta V_{io} = \frac{V_{io} \text{ drift}}{\sqrt{(\text{months})}}$$

where  $V_{io}$  drift is the measured drift value in the specified test conditions after 1000 h stress duration.

## 4.6 Initialization time

The OA1MPA, OA2MPA, and OA4MPA series of devices use a proprietary trimming topology that is initiated at each device power-up and allows excellent  $V_{io}$  performance to be achieved. The initialization time is defined as the delay after power-up which guarantees operation within specified performances. During this period, the current consumption ( $I_{CC}$ ) and the input offset voltage ( $V_{io}$ ) can be different to the typical ones.

**Figure 22. Initialization phase**



The initialization time is  $V_{CC}$  and temperature dependent. [Table 7](#) sums up the measurement results for different supply voltages and for temperatures varying from -40 °C to 125 °C.

**Table 7. Initialization time measurement results**

| $V_{CC}$ (V) | Temperature: -40 °C |                       | Temperature: 25 °C |                       | Temperature: 125 °C |                       |
|--------------|---------------------|-----------------------|--------------------|-----------------------|---------------------|-----------------------|
|              | $T_{init}$ (ms)     | $I_{CC}$ phase 1 (mA) | $T_{init}$ (ms)    | $I_{CC}$ phase 1 (mA) | $T_{init}$ (ms)     | $I_{CC}$ phase 1 (mA) |
| 1.8          | 37                  | 0.33                  | 3.2                | 0.40                  | 0.35                | 0.46                  |
| 3.3          | 2.9                 | 1.4                   | 0.95               | 1.3                   | 0.34                | 1.2                   |
| 5            | 2.4                 | 3.2                   | 0.85               | 2.4                   | 0.31                | 2.9                   |

## 4.7 PCB layouts

For correct operation, it is advised to add a 10 nF decoupling capacitors as close as possible to the power supply pins.

## 4.8 Macromodel

Accurate macromodels of the OA1MPA, OA2MPA, and OA4MPA devices are available on the STMicroelectronics' website at [www.st.com](http://www.st.com). These model are a trade-off between accuracy and complexity (that is, time simulation) of the OA1MPA, OA2MPA, and OA4MPA op amp. They emulate the nominal performance of a typical device within the specified operating conditions mentioned in the datasheet. They also help to validate a design approach and to select the right op amp, *but they do not replace on-board measurements*.

## 5 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: [www.st.com](http://www.st.com). ECOPACK® is an ST trademark.

## 5.1 SC70-5 package information

Figure 23. SC70-5 package mechanical drawing

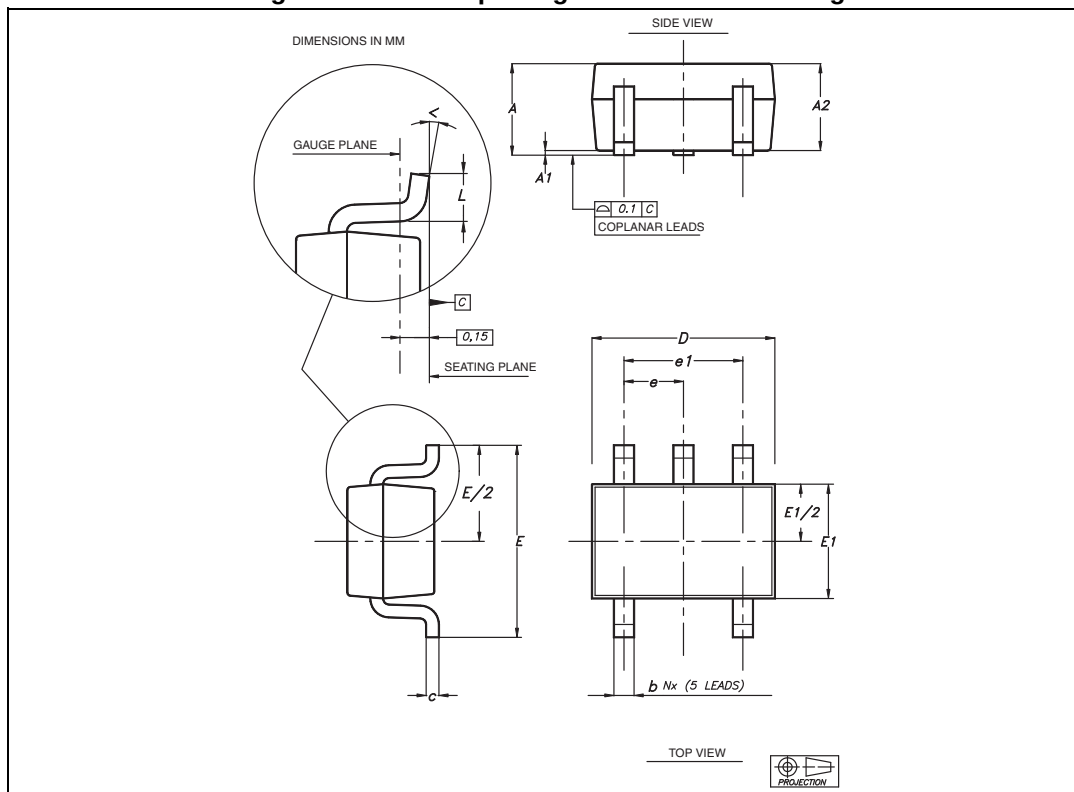


Table 8. SC70-5 package mechanical data

| Symbol | Dimensions  |      |      |        |       |       |
|--------|-------------|------|------|--------|-------|-------|
|        | Millimeters |      |      | Inches |       |       |
|        | Min.        | Typ. | Max. | Min.   | Typ.  | Max.  |
| A      | 0.80        |      | 1.10 | 0.032  |       | 0.043 |
| A1     | 0           |      | 0.10 |        |       | 0.004 |
| A2     | 0.80        | 0.90 | 1.00 | 0.032  | 0.035 | 0.039 |
| b      | 0.15        |      | 0.30 | 0.006  |       | 0.012 |
| c      | 0.10        |      | 0.22 | 0.004  |       | 0.009 |
| D      | 1.80        | 2.00 | 2.20 | 0.071  | 0.079 | 0.087 |
| E      | 1.80        | 2.10 | 2.40 | 0.071  | 0.083 | 0.094 |
| E1     | 1.15        | 1.25 | 1.35 | 0.045  | 0.049 | 0.053 |
| e      |             | 0.65 |      |        | 0.025 |       |
| e1     |             | 1.30 |      |        | 0.051 |       |
| L      | 0.26        | 0.36 | 0.46 | 0.010  | 0.014 | 0.018 |
| <      | 0°          |      | 8°   | 0°     |       | 8°    |



### 5.3 MiniSO-8 package information

Figure 25. MiniSO-8 package mechanical drawing

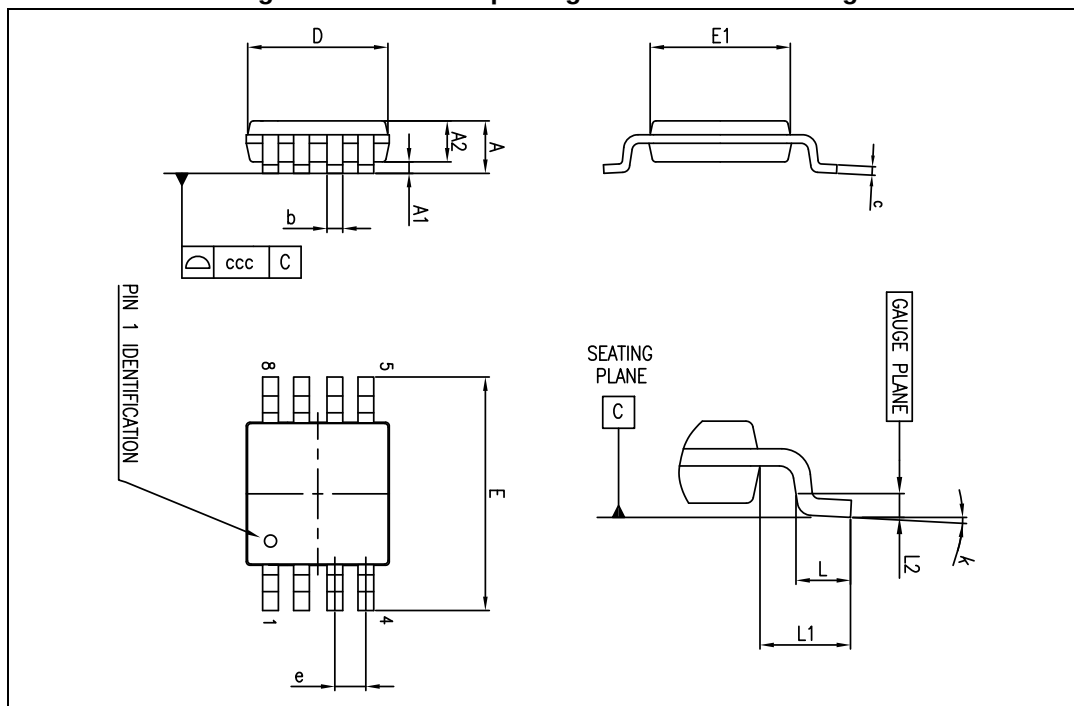


Table 10. MiniSO-8 package mechanical data

| Ref. | Dimensions  |      |      |        |       |       |
|------|-------------|------|------|--------|-------|-------|
|      | Millimeters |      |      | Inches |       |       |
|      | Min.        | Typ. | Max. | Min.   | Typ.  | Max.  |
| A    |             |      | 1.1  |        |       | 0.043 |
| A1   | 0           |      | 0.15 | 0      |       | 0.006 |
| A2   | 0.75        | 0.85 | 0.95 | 0.030  | 0.033 | 0.037 |
| b    | 0.22        |      | 0.40 | 0.009  |       | 0.016 |
| c    | 0.08        |      | 0.23 | 0.003  |       | 0.009 |
| D    | 2.80        | 3.00 | 3.20 | 0.11   | 0.118 | 0.126 |
| E    | 4.65        | 4.90 | 5.15 | 0.183  | 0.193 | 0.203 |
| E1   | 2.80        | 3.00 | 3.10 | 0.11   | 0.118 | 0.122 |
| e    |             | 0.65 |      |        | 0.026 |       |
| L    | 0.40        | 0.60 | 0.80 | 0.016  | 0.024 | 0.031 |
| L1   |             | 0.95 |      |        | 0.037 |       |
| L2   |             | 0.25 |      |        | 0.010 |       |
| k    | 0 °         |      | 8 °  | 0 °    |       | 8 °   |
| ccc  |             |      | 0.10 |        |       | 0.004 |

## 5.4 QFN16 3x3 package information

Figure 26. QFN16 3x3 package mechanical drawing

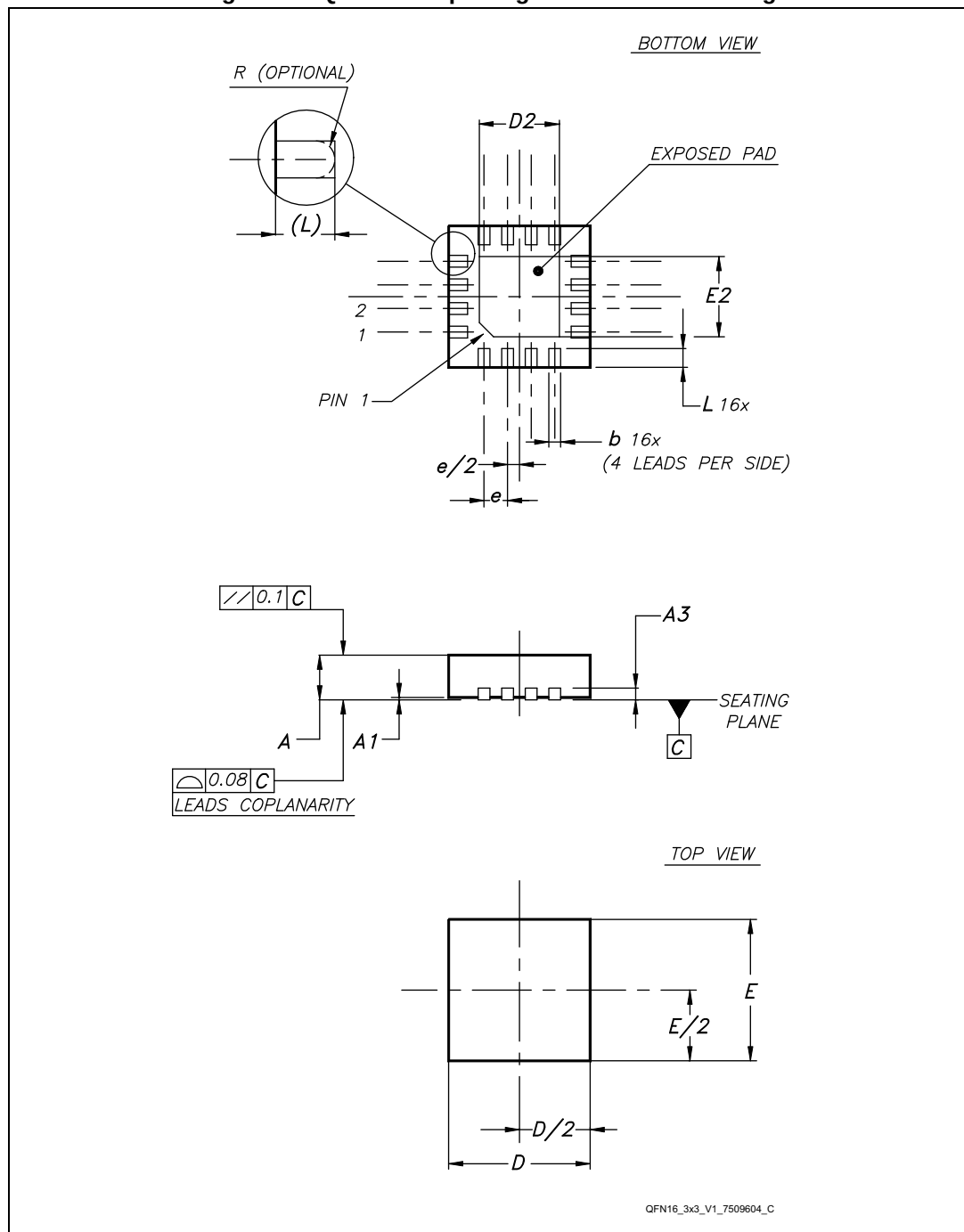
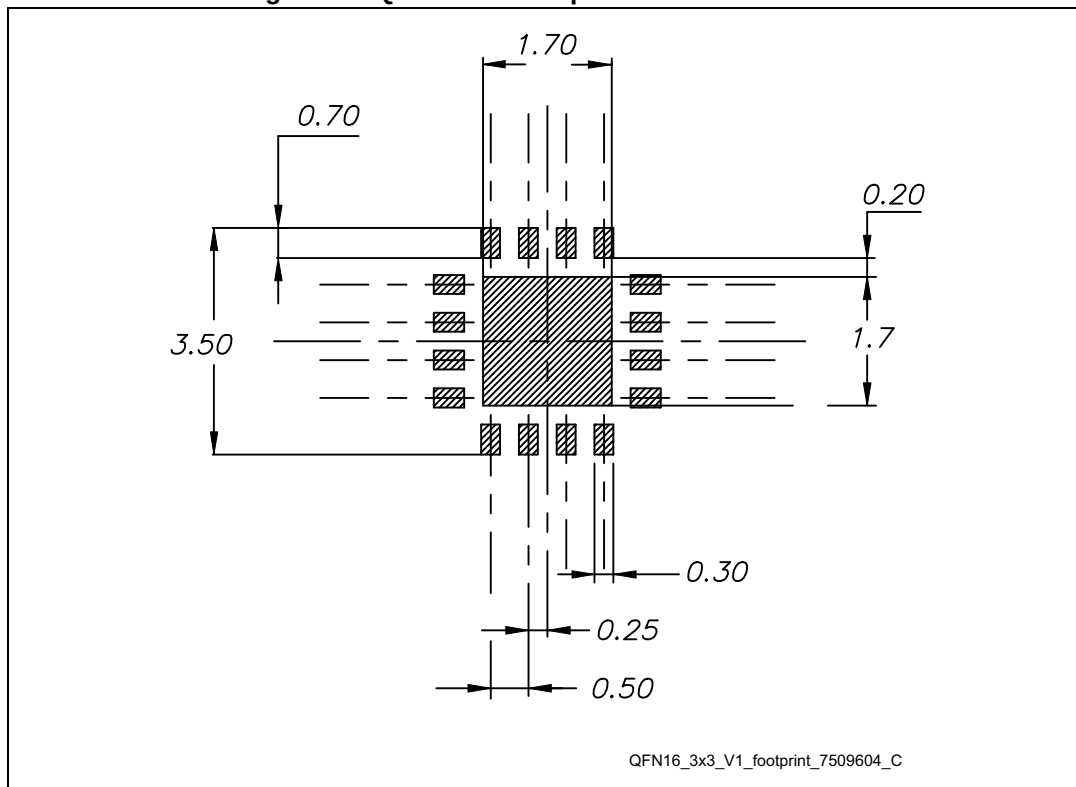


Table 11. QFN16 3x3 mm package mechanical data (pitch 0.5 mm)

| Ref. | Dimensions  |      |      |        |       |       |
|------|-------------|------|------|--------|-------|-------|
|      | Millimeters |      |      | Inches |       |       |
|      | Min.        | Typ. | Max. | Min.   | Typ.  | Max.  |
| A    | 0.80        | 0.90 | 1.00 | 0.031  | 0.035 | 0.039 |
| A1   | 0           |      | 0.05 | 0      |       | 0.002 |
| A3   |             | 0.20 |      |        | 0.008 |       |
| b    | 0.18        |      | 0.30 | 0.007  |       | 0.012 |
| D    | 2.90        | 3.00 | 3.10 | 0.114  | 0.118 | 0.122 |
| D2   | 1.50        |      | 1.80 | 0.059  |       | 0.071 |
| E    | 2.90        | 3.00 | 3.10 | 0.114  | 0.118 | 0.122 |
| E2   | 1.50        |      | 1.80 | 0.059  |       | 0.071 |
| e    |             | 0.50 |      |        | 0.020 |       |
| L    | 0.30        |      | 0.50 | 0.012  |       | 0.020 |

Figure 27. QFN16 3x3 footprint recommendation



## 6 Revision history

**Table 12. Document revision history**

| Date        | Revision | Changes         |
|-------------|----------|-----------------|
| 28-Feb-2014 | 1        | Initial release |

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